

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

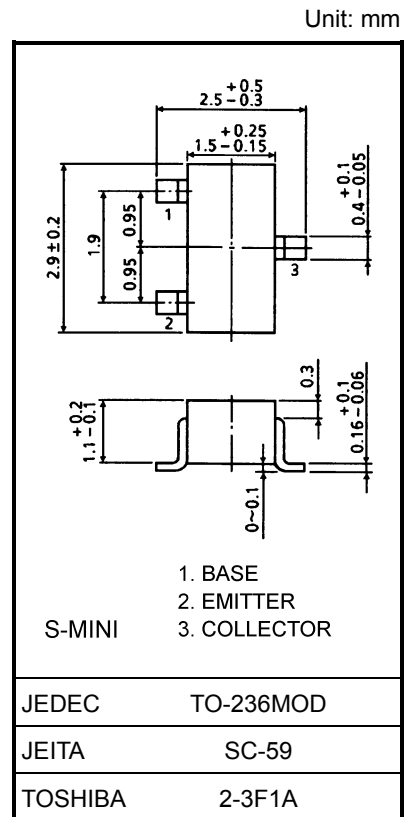
# 2SC2713

## Audio Frequency General Purpose Amplifier Applications

- High voltage:  $V_{CEO} = 120\text{ V}$
- Excellent  $h_{FE}$  linearity:  $h_{FE}(I_C = 0.1\text{ mA})/h_{FE}(I_C = 2\text{ mA}) = 0.95$  (typ.)
- High  $h_{FE}$ :  $h_{FE} = 200\sim 700$
- Low noise:  $NF = 1\text{ dB}$  (typ.),  $10\text{ dB}$  (max)
- Complementary to 2SA1163
- Small package

### Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	120	V
Collector-emitter voltage	$V_{CEO}$	120	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	100	mA
Base current	$I_B$	20	mA
Collector power dissipation	$P_C$	150	mW
Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55~125	$^\circ\text{C}$



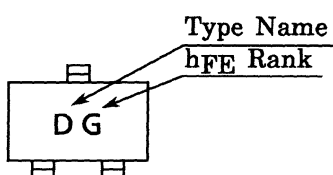
Weight: 0.012 g (typ.)

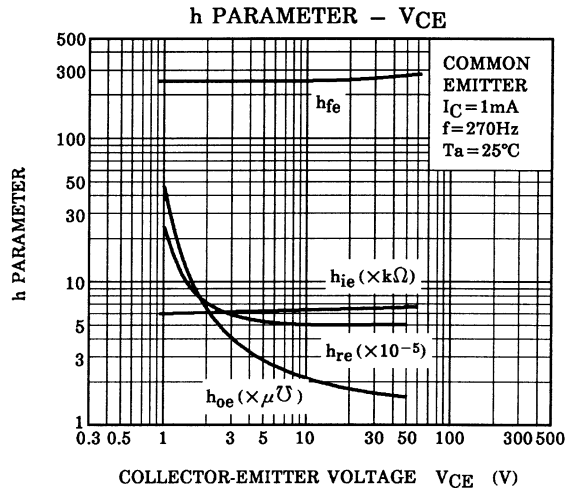
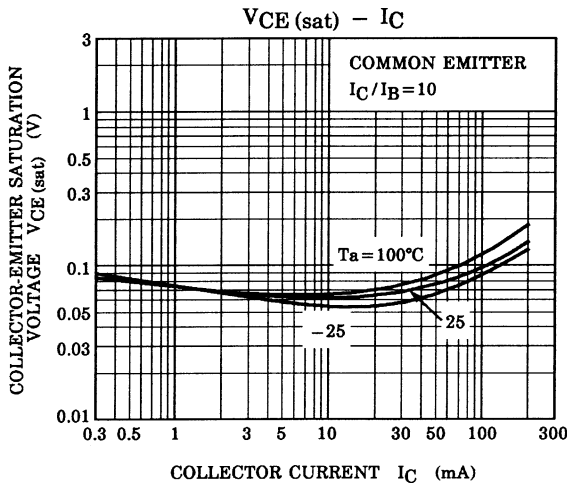
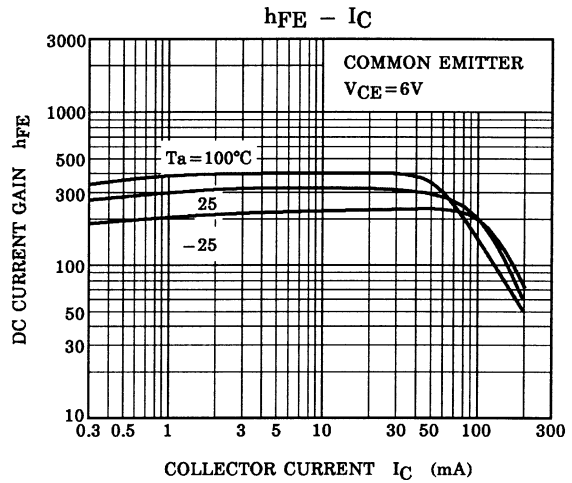
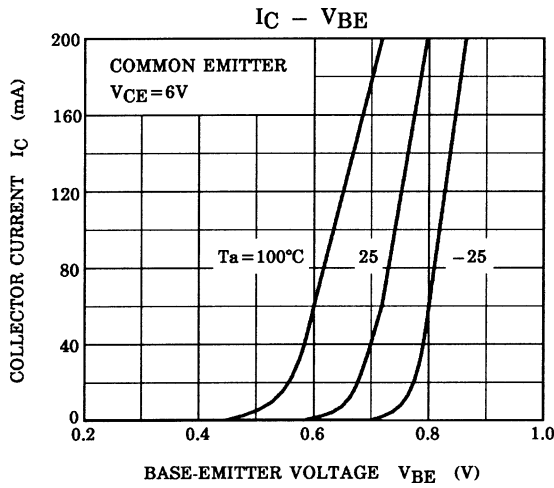
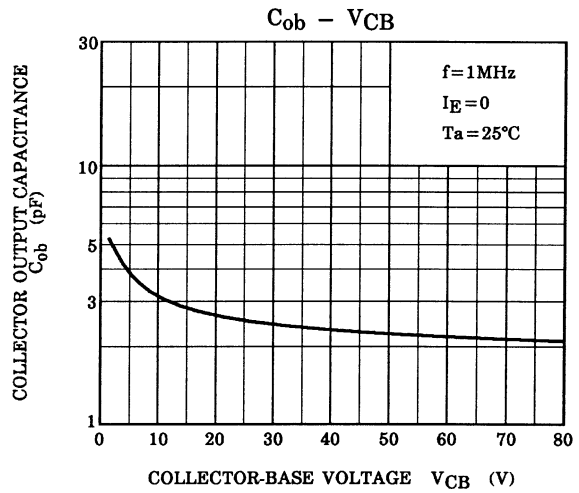
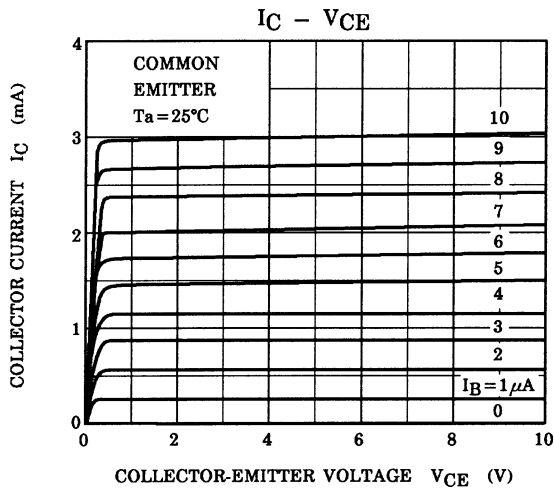
### Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

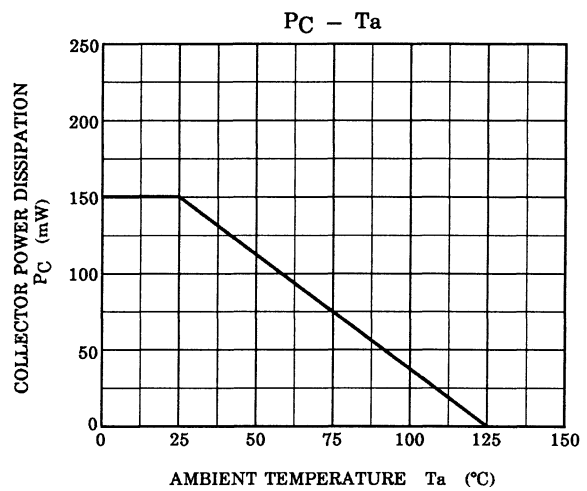
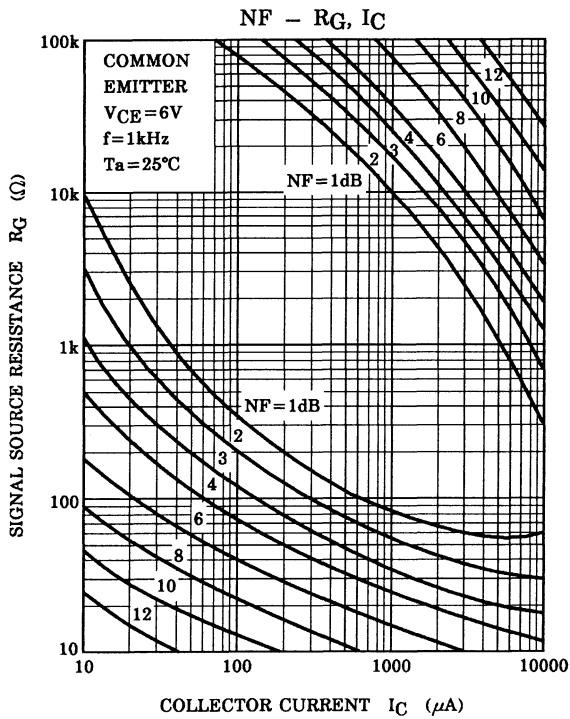
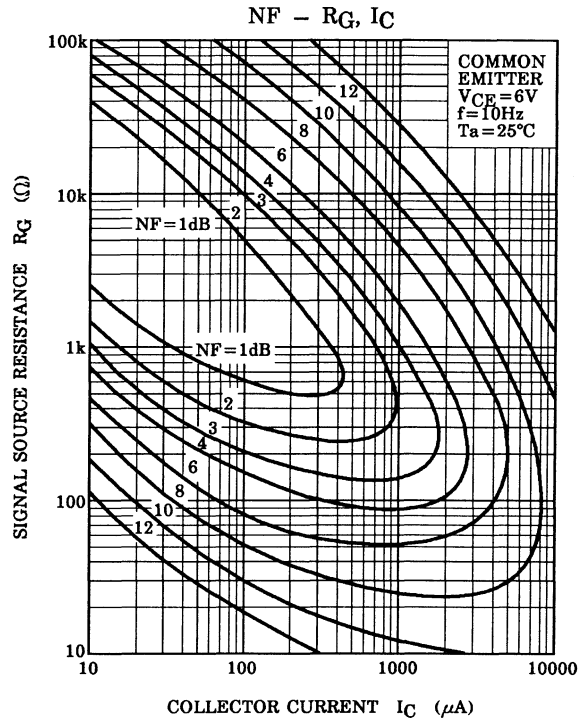
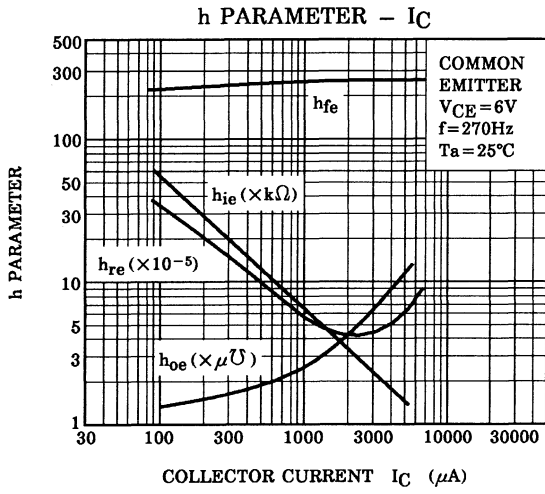
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = 120\text{ V}, I_E = 0$	—	—	0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	0.1	$\mu\text{A}$
DC current gain	$h_{FE}$ (Note)	$V_{CE} = 6\text{ V}, I_C = 2\text{ mA}$	200	—	700	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10\text{ mA}, I_B = 1\text{ mA}$	—	—	0.3	V
Transition frequency	$f_T$	$V_{CE} = 6\text{ V}, I_C = 1\text{ mA}$	—	100	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3.0	—	pF
Noise figure	NF	$V_{CE} = 6\text{ V}, I_C = 0.1\text{ mA}$ $f = 1\text{ kHz}, R_G = 10\text{ k}\Omega$	—	1.0	10	dB

Note:  $h_{FE}$  classification GR (G): 200~400, BL (L): 350~700

### Marking







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